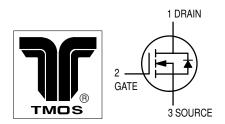
# **TMOS FET Switching**

N-Channel — Enhancement



### MAXIMUM RATINGS

| Rating   | Symbol                              | Value       | Unit       |  |
|--|-------------------------------------|-------------|------------|--|
| Drain-Source Voltage   | V <sub>DS</sub>                     | 60          | Vdc        |  |
| Gate–Source Voltage<br>— Continuous<br>— Non–repetitive (t <sub>p</sub> ≤ 50 μs) | V <sub>GS</sub><br>V <sub>GSM</sub> | ±20<br>±40  | Vdc<br>Vpk |  |
| Drain Current <sup>(1)</sup>   | ١D                                  | 0.5         | Adc        |  |
| Total Device Dissipation @ $T_A = 25^{\circ}C$                                   | PD                                  | 350         | mW         |  |
| Operating and Storage Junction<br>Temperature Range                              | TJ, T <sub>stg</sub>                | -55 to +150 | °C         |  |



**BS170** 

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   | Symbol                | Min | Тур  | Max | Unit  |
|--|-----------------------|-----|------|-----|-------|
| OFF CHARACTERISTICS  |                       |     |      |     |       |
| Gate Reverse Current<br>(V <sub>GS</sub> = 15 Vdc, V <sub>DS</sub> = 0)                    | IGSS                  | -   | 0.01 | 10  | nAdc  |
| Drain–Source Breakdown Voltage $(V_{GS} = 0, I_D = 100 \ \mu Adc)$                         | V <sub>(BR)</sub> DSS | 60  | 90   | —   | Vdc   |
| ON CHARACTERISTICS <sup>(2)</sup>  |                       | •   |      |     |       |
| Gate Threshold Voltage<br>(V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mAdc)  | VGS(Th)               | 0.8 | 2.0  | 3.0 | Vdc   |
| Static Drain–Source On Resistance<br>(V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 200 mAdc) | <sup>r</sup> DS(on)   | —   | 1.8  | 5.0 | Ω     |
| Drain Cutoff Current<br>(V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0 Vdc)                | <sup>I</sup> D(off)   | —   | —    | 0.5 | μΑ    |
| Forward Transconductance<br>(V <sub>DS</sub> = 10 Vdc, I <sub>D</sub> = 250 mAdc)          | 9fs                   | —   | 200  | —   | mmhos |
| SMALL-SIGNAL CHARACTERISTICS   |                       | •   | •    |     | •     |
| Input Capacitance<br>(V <sub>DS</sub> = 10 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)          | C <sub>iss</sub>      | _   | —    | 60  | pF    |
| SWITCHING CHARACTERISTICS  |                       |     | •    |     |       |
| Turn–On Time<br>(I <sub>D</sub> = 0.2 Adc) See Figure 1                                    | ton                   | _   | 4.0  | 10  | ns    |
| Turn–Off Time<br>(I <sub>D</sub> = 0.2 Adc) See Figure 1                                   | toff                  | _   | 4.0  | 10  | ns    |

1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

# **RESISTIVE SWITCHING**

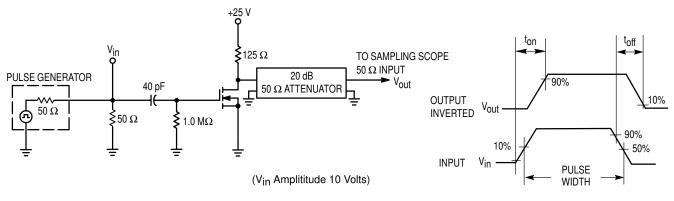


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

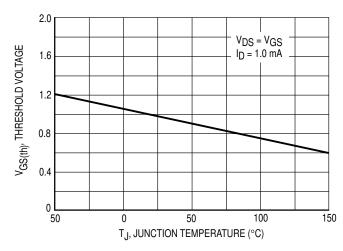


Figure 3. VGS(th) Normalized versus Temperature

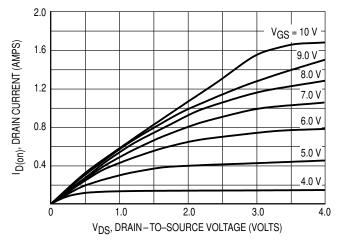
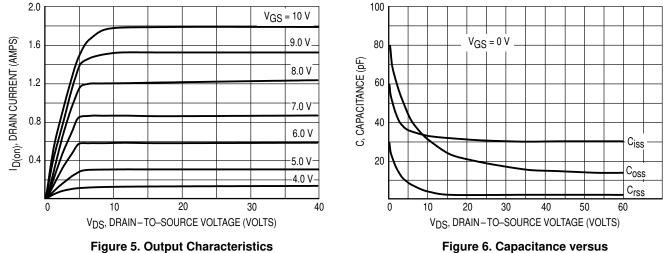
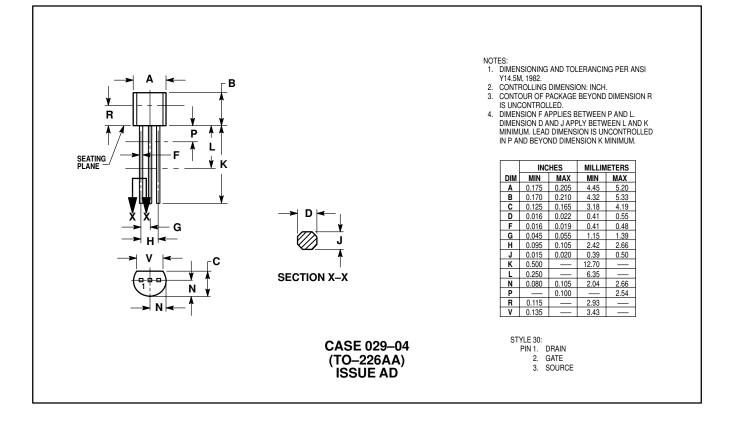


Figure 4. On–Region Characteristics



Drain–To–Source Voltage

## PACKAGE DIMENSIONS



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